



IHW30N100R Information

For Reference Only

Part Number IHW30N100R

Manufacturer Infineon Technologies

Category Discrete Semiconductor Products

Transistors - IGBTs - Single

Description IGBT 1000V 60A 412W TO247-3

TO-247-3 **Package**

For the pricing/inventory/lead time, please contact

Website: https://www.heisener.com

E-mail: salesdept@heisener.com



Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









IHW30N100R Specifications

Manufacturer Part Number	IHW30N100R
Manufacturer	Infineon Technologies
Category	Discrete Semiconductor Products
	Transistors - IGBTs - Single
Package	TO-247-3
Series	-
IGBT Type	Trench Field Stop
Voltage - Collector Emitter Breakdown (Max)	1000V
Current - Collector (Ic) (Max)	60A
Current - Collector Pulsed (Icm)	90A
Vce(on) (Max) @ Vge, Ic	1.7V @ 15V, 30A
Power - Max	412W
Switching Energy	2.1mJ (off)
Input Type	Standard
Gate Charge	209nC
Td (on/off) @ 25°C	-/846ns
Test Condition	600V, 30A, 26 Ohm, 15V
Reverse Recovery Time (trr)	-
Operating Temperature	-40°C ~ 175°C (TJ)
Mounting Type	Through Hole
Package / Case	TO-247-3
Supplier Device Package	PG-TO247-3
	Report errors?

IHW30N100R Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

IHW30N100R Payment Methods





















IHW30N100R Shipping Methods













If you have any question about IHW30N100R, please do not hesitate to contact us!

Website: https://www.heisener.com E-mail: salesdept@heisener.com